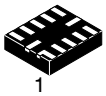
NCN9252

High-Speed USB 2.0 (480 Mbps) DP3T Switch for USB/UART/Data Multiplexing

ON Semiconductor®

http://onsemi.com



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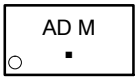
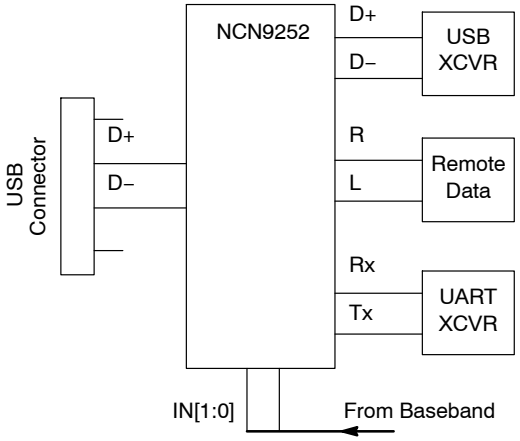
UQFN12
MU SUFFIX
CASE 523AE

MARKING DIAGRAM



AD = Specific Device Code
M = Date Code
▪ = Pb−Free Package

APPLICATION DIAGRAM



Brief Description

The NCN9252 is a DP3T switch for combined UART and USB 2.0 high−speed data applications. It allows portable systems to use a single external port to transmit and receive signals to and from three separate locations within the portable system. It is comprised of two switches, each with a single common I/O that alternates between 3 terminals. They are operated together to allow three data sources, such as a USB or UART transceiver, to pass differential data through a shared USB connector port.

The NCN9252 features low R_{ON}− 4 Ω (max) at 4.2 V V_{CC}, 5 Ω (typ) at a 3.3 V V_{CC}. It also features low C_{ON}, < 30 pF (max) across the supply voltage range. This performance makes it ideal for both USB full−speed and high−speed applications that require both low R_{ON} and C_{ON} for effective signal transmission.

The NCN9252 is capable of accepting control input signals down to 1.4 V, over a range of V_{CC} supply voltages with minimal leakage current. The NCN9252 is offered in a Pb−Free, 12 pin, 1.7 x 2.0 x 0.5 mm, UQFN package.

Features

- USB 2.0 Signal Routing
- −3 dB Bandwidth: 525 MHz
- R_{ON}: 4 Ω Max @ V_{CC} = 4.2 V
- C_{ON}: < 20 pF @ V_{CC} = 3.3 V
- OVT Protection up to 5.25 V on Common Pins
- V_{CC} Range: 1.65 V to 4.5 V
- 3 kV ESD Protection
- 1.7 x 2.0 x 0.5 mm UQFN12 Package
- This is a Pb−Free Device

Typical Applications

- USB/UART/Data Multiplexing
- Shared USB Connector
- Mobile Phones
- Portable Devices

ORDERING INFORMATION

Device	Package	Shipping†
NCN9252MUTAG	UQFN12 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

FUNCTIONAL BLOCK DIAGRAM AND PINOUT

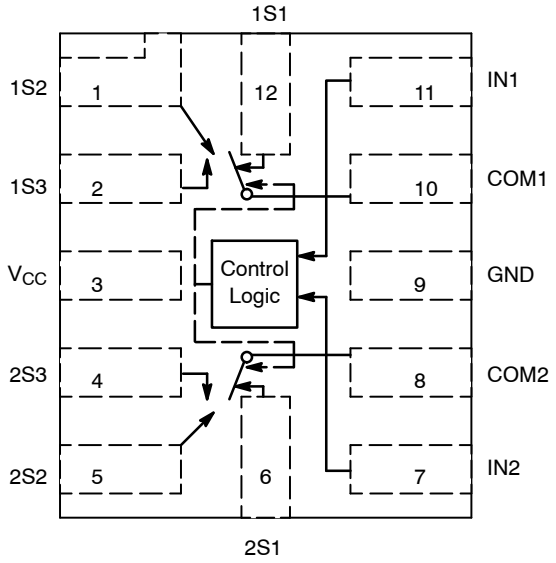


Figure 1. Internal Block Diagram

PIN DESCRIPTIONS

Pin#	Name	Direction	Description
1	1S2	I/O	Switch #1 Position 2 Signal Line
2	1S3	I/O	Switch #1 Position 3 Signal Line
3	V_{CC}	Input	Power Supply
4	2S3	I/O	Switch #2 Position 3 Signal Line
5	2S2	I/O	Switch #2 Position 2 Signal Line
6	2S1	I/O	Switch #2 Position 1 Signal Line
7	IN2	Input	Bit 1 Control Input Select Line
8	COM2	I/O	Switch #2 Common Signal Line
9	GND	Input	Ground
10	COM1	I/O	Switch #1 Common Signal Line
11	IN1	Input	Bit 0 Control Input Select Line
12	1S1	I/O	Switch #1 Position 1 Signal Line

FUNCTION TABLE

IN1 [0]	IN2 [1]	COM1 Closed to:	COM2 Closed to:
0	0	No Connect	No Connect
1	0	1S1	2S1
0	1	1S2	2S2
1	1	1S3	2S3

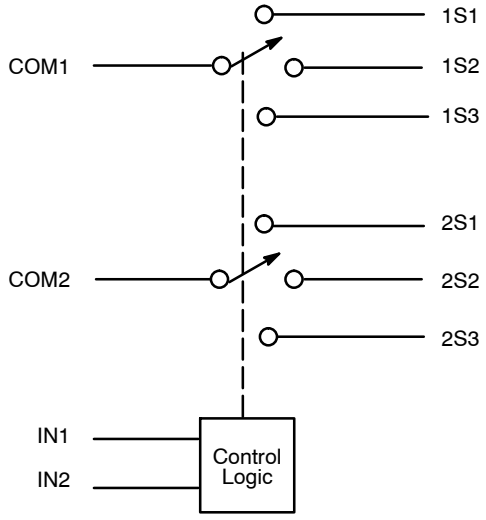


Figure 2. Functional Block Diagram

OPERATING CONDITIONS

MAXIMUM RATINGS

Symbol	Pins	Parameter	Value	Condition	Unit
V_{CC}	V_{CC}	Positive DC Supply Voltage	−0.5 to +5.5		V
V_{IS}	1Sx, 2Sx	Analog Signal Voltage	−0.5 to V_{CC} + 0.3		V
	COMx		−0.5 to 5.3		
V_{IN}	IN1, IN2	Control Input Voltage	−0.5 to 4.6		V
I_{CC}	V_{CC}	Positive DC Supply Current	50		mA
I_{IS_CON}	1Sx, 2Sx COMx	Analog Signal Continuous Current	±300	Closed Switch	mA
I_{IS_PK}	1Sx, 2Sx COMx	Analog Signal Peak Current	±500	10% Duty Cycle	mA
I_{IN}	IN1, IN2	Control Input Current	±20		mA
T_{STG}		Storage Temperature Range	−65 to 150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Symbol	Pins	Parameter	Value	Condition	Unit
V_{CC}	V_{CC}	Positive DC Supply Voltage	1.65 to 4.5		V
V_{IS}	1Sx, 2Sx	Analog Signal Voltage	GND to V_{CC}		V
	COMx		GND to 4.5		
V_{IN}	IN1, IN2	Control Input Voltage	GND to V_{CC}		V
T_A		Operating Temperature Range	−40 to 85		°C

Minimum and maximum values are guaranteed through test or design across the **Recommended Operating Conditions**, where applicable. Typical values are listed for guidance only and are based on the particular conditions listed for each section, where applicable. These conditions are valid for all values found in the characteristics tables unless otherwise specified in the test conditions.

ESD PROTECTION

Pins	Description	Minimum Voltage
All Pins	Human Body Model	3 kV

DC ELECTRICAL CHARACTERISTICS

CONTROL INPUT (TYPICAL: T = 25°C; V_{CC} = 3.3 V)

Symbol	Pins	Parameter	Test Conditions	V_{CC}	Min	Typ	Max	Unit
V_{IH}	INx	Control Input High	**Figures 3**	2.7 V 3.3 V 4.2 V	1.25 1.35 1.50			V
V_{IL}	INx	Control Input Low	**Figures 3**	2.7 V 3.3 V 4.2 V			0.4 0.4 0.5	V
I_{IN}	INx	Control Input Leakage	V_{IS} = GND				±1.0	μA

SUPPLY CURRENT AND LEAKAGE (TYPICAL: T = 25°C; V_{CC} = 3.3 V, V_{IN} = V_{CC} or GND)

Symbol	Pins	Parameter	Test Conditions	V_{CC}	Min	Typ	Max	Unit
$I_{NO/NC}$ (OFF)	NC, NO	OFF State Leakage	V_{COM} = 3.6 V V_{NC} = 1.0 V				±1.0	μA
I_{COM} (ON)	COM	ON State Leakage					±1.0	μA
I_{CC}	V_{CC}	Quiescent Supply	V_{IS} = V_{CC} or GND, I_D = 0;				1.0	μA
IOFF		Power OFF Leakage	V_{IS} = GND				1.0	μA

ON RESISTANCE (TYPICAL: T = 25°C; V_{CC} = 3.3 V)

Symbol	Pins	Parameter	Test Conditions	V_{CC}	Min	Typ	Max	Unit
R_{ON}	1Sx, 2Sx COMx	ON Resistance	I_{ON} = −8 mA, V_{IS} = 0 to V_{CC};	2.7 V 3.3 V 4.2 V		5 4 3.5	6 5 4.5	Ω
R_{FLAT}	1Sx, 2Sx COMx	R_{ON} Flatness	I_{ON} = −8 mA, V_{IS} = 0 to V_{CC};	2.7 V 3.3 V 4.2 V			1.3 1.4 1.6	Ω
ΔR_{ON}	1Sx, 2Sx COMx	R_{ON} Matching	I_{ON} = −8 mA, V_{IS} = 0 to V_{CC};	2.7 V 3.3 V 4.2 V		0.35		Ω

AC ELECTRICAL CHARACTERISTICS

TIMING/FREQUENCY (TYPICAL: T = 25°C; V_{CC} = 3.3 V, R_L = 50 Ω, C_L = 5 pF, f = 1 MHz)

Symbol	Pins	Parameter	Test Conditions	Min	Typ	Max	Unit
BW		−3 dB Bandwidth			525		MHz
THD		Total Harmonic Distortion	20 Hz to 20 kHz, 1.0 V_{PP}		0.01		%
t_{ON}	1Sx to 1Sy, 2Sx to 2Sy	Turn On Time			13	30	nS
t_{OFF}	1Sy to 1Sx, 2Sy to 2Sx	Turn Off Time			12	25	nS
t_{BBM}	1Sx to 1Sy, 2Sx to 2Sy	Break Before Make		2.0			nS

CROSSTALK: (TYPICAL: T = 25°C; V_{CC} = 3.3V, R_L = 50 Ω, C_L = 35 pF, f = 1MHz)

Symbol	Pins	Parameter	Test Conditions	Min	Typ	Max	Unit
O_{IRR}	1Sx or 2Sx	Off Isolation	V_{IN} = 0		−60		dB
X_{talk}	COMx to COMy	Non−Adjacent Channel			−60		dB

CAPACITANCE (TYPICAL: T = 25°C; V_{CC} = 3.3V, R_L = 50 Ω, C_L = 5 pF, f = 1 MHz)

Symbol	Pins	Parameter	Test Conditions	Min	Typ	Max	Unit
C_{IN}	INx	Control Input	V_{CC} = 0 V		3		pF
C_{ON}	1Sx or 2Sx to COM	Through Switch	V_{CC} = 3.3 V, V_{IN} = 0 V		16	20	pF
C_{OFF}	1Sx, 2Sx COMx	Unselected Port	V_{CC} = V_{IN} = 3.3 V		8		pF

Detailed Description

The NCN9252 is a DP3T switch designed for applications where a single USB connector is used for multiple data applications within a portable system. Two differential signals from a USB connector can be routed to 3 different end locations. The first, channel 1, is optimized for a high−speed, USB 2.0 transceiver. The second and third, channels 2 and 3, are optimized for UART or remote data applications.

Control Inputs Select Logic

The NCN9252 is made up of two, 3−throw switches operating off of the same internal enable signal. For each switch, a signal can pass from the common pin to any of three terminals. Whenever COM1 is closed to terminal 1S2, COM2 will respectively be closed to terminal 2S2. The select logic is controlled by two inputs, IN1 and IN2, connecting the common pins to the terminals according to the function table found on page 2. Since there are four possible control states but only 3 possible terminals, the first combination results in a open connection for all three terminals.

V_{IH} and V_{IL} Levels

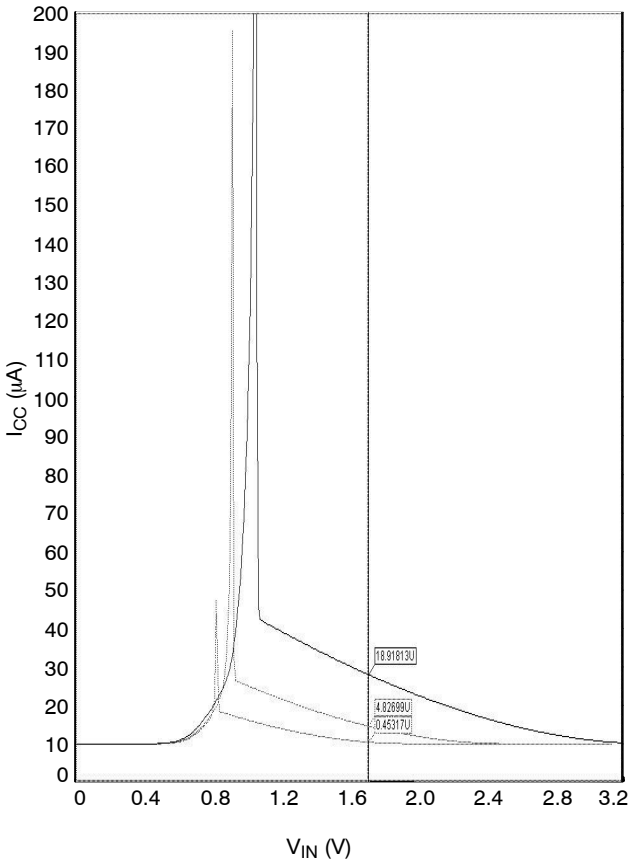


Figure 3. I_{CC} Leakage Current vs. V_{IN}

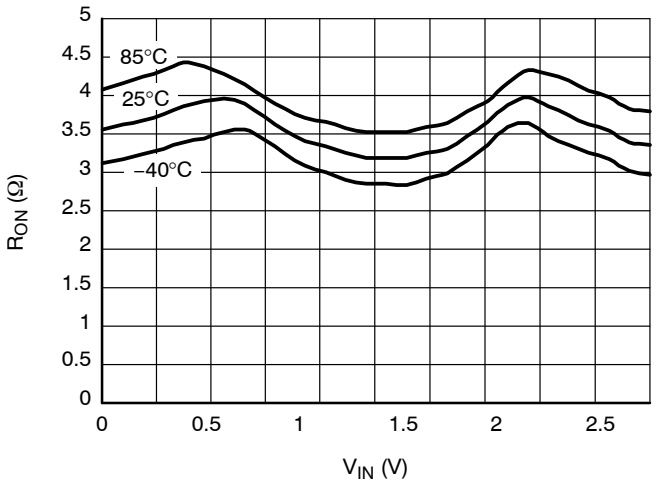


Figure 4. On−Resistance vs. Input Voltage @ V_{CC} = 2.7 V

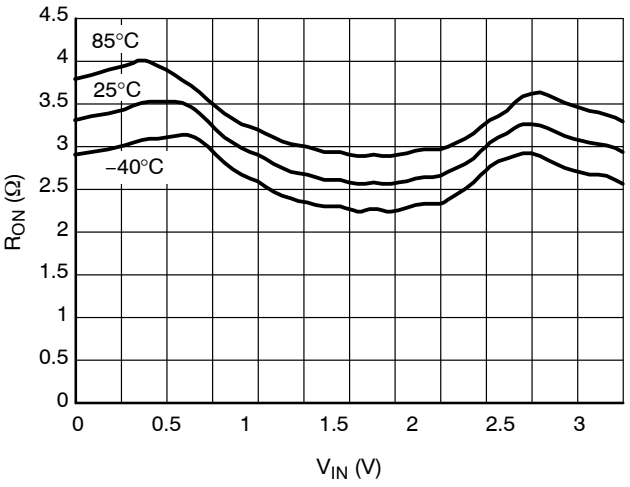


Figure 5. On−Resistance vs. Input Voltage @ V_{CC} = 3.3 V

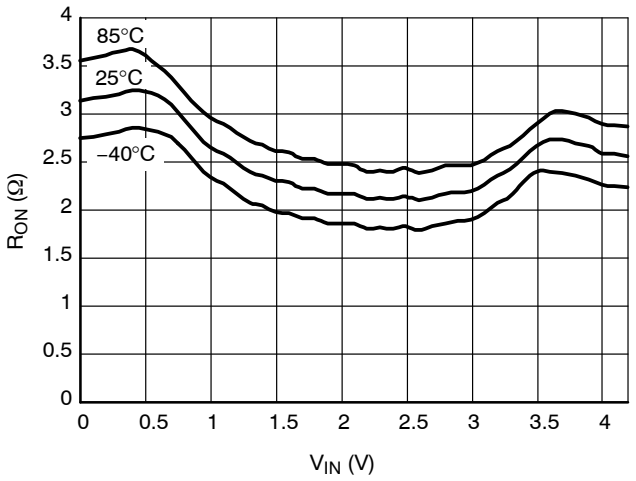


Figure 6. On−Resistance vs. Input Voltage @ V_{CC} = 4.2 V

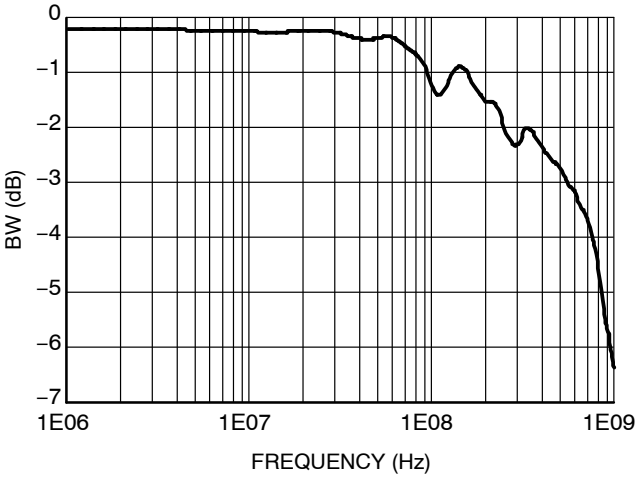


Figure 7. Bandwidth vs. Frequency

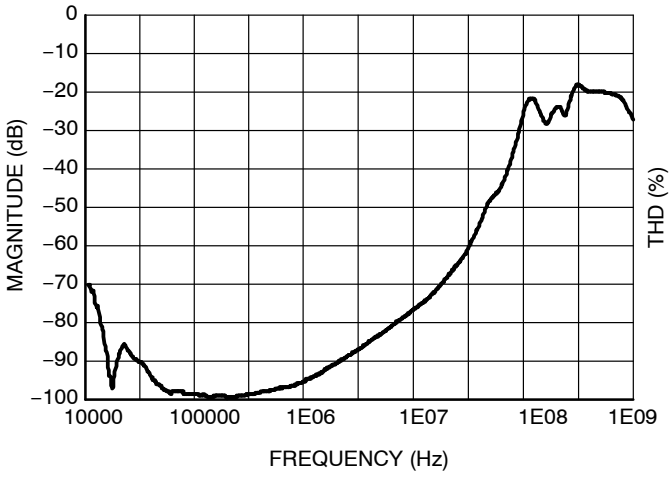


Figure 8. Cross Talk vs. Frequency @ 25°C

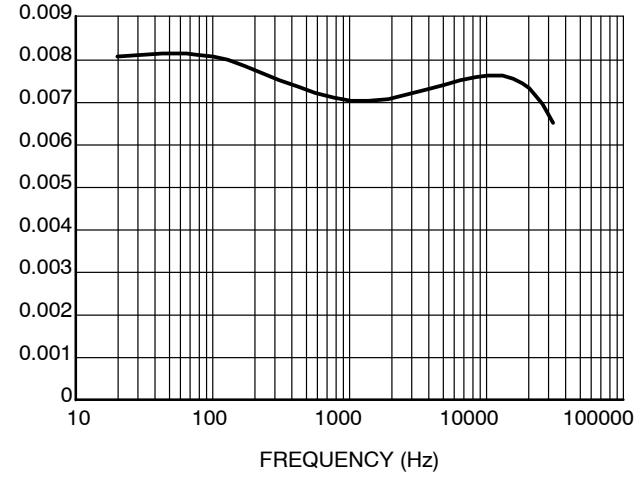
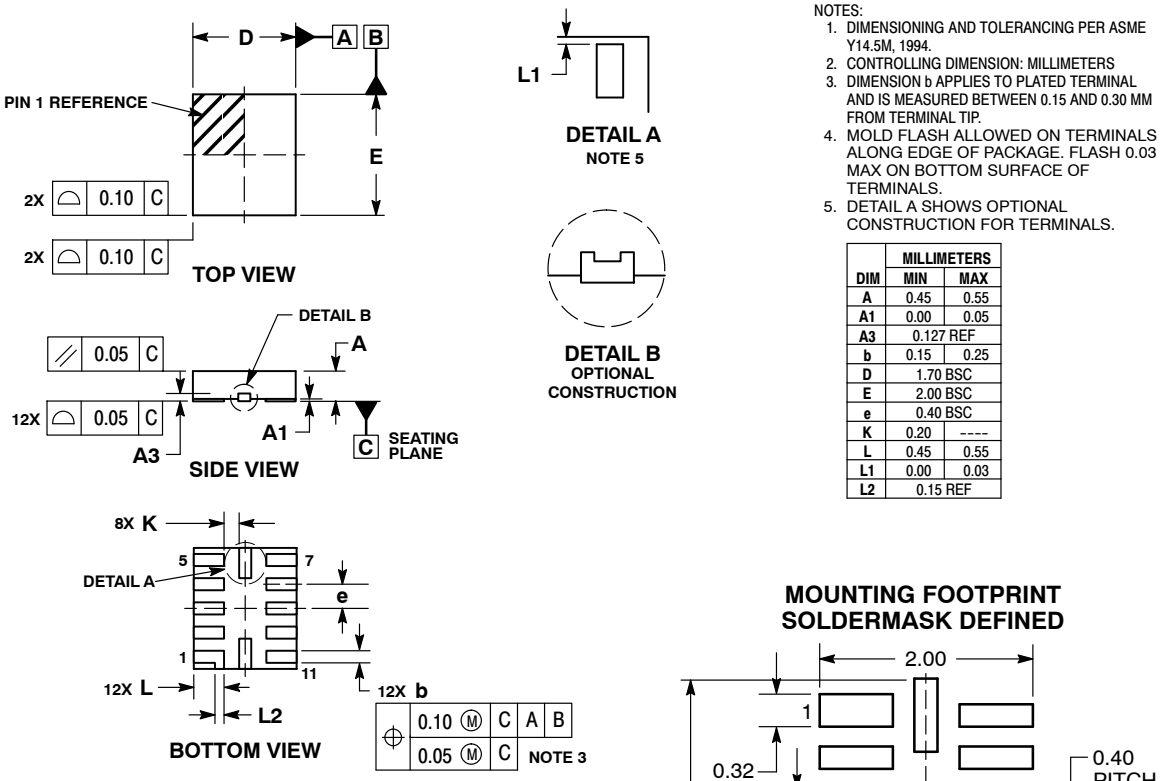


Figure 9. Total Harmonic Distortion vs. Frequency

PACKAGE DIMENSIONS

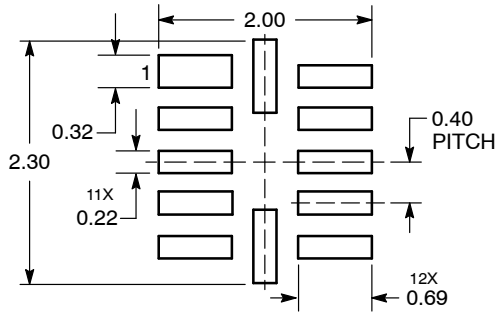
UQFN12 1.7x2.0, 0.4P
CASE 523AE−01
ISSUE A



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 MM FROM TERMINAL TIP.
4. MOLD FLASH ALLOWED ON TERMINALS ALONG EDGE OF PACKAGE. FLASH 0.03 MAX ON BOTTOM SURFACE OF TERMINALS.
5. DETAIL A SHOWS OPTIONAL CONSTRUCTION FOR TERMINALS.

	MILLIMETERS	
DIM	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.127 REF	
b	0.15	0.25
D	1.70 BSC	
E	2.00 BSC	
e	0.40 BSC	
K	0.20	----
L	0.45	0.55
L1	0.00	0.03
L2	0.15 REF	

MOUNTING FOOTPRINT
SOLDERMASK DEFINED



DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
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